

ACT1GEU64S8F667S
1GB DDR2-667 Unbuffered non-ECC DIMM

Description

ACTICA ACT1GEU64S8F667S is a high speed 1GB DDR2-667 Unbuffered non-ECC DIMM . It is designed for mission critical application memory solution. The modules is constructed using Samsung SDRAMs, and is fully compliant with JEDEC specifications. Decoupling capacitors are mounted on the PCB board for better signal integrity. The DIMM feature serial presence detect (SPD) based on a serial EEPROM device using the 2-pin I2C protocol.

Features	Value
ACTICA memory P/N	ACT1GEU64S8F667S
CL-tRCD-tRP	5-5-5
RoHS compliant	Yes
Supply Voltage	1.8V ± 0.1V
JEDEC standard	Yes
Operating Temperature*	0 - 95 °C
Timing Parameter:	
tCK (Clock Cycle Time)	3ns
tRCD (Ras and Cas Delay)	15ns
tRP (Row Precharge Time)	15ns
tRAS (Row Active Time)	45ns
tIH (Input Hold Time)	275ps
tIS (Input Setup Time)	200ps
Operating Current:	
IDD0 (Operating one bank active-precharge current)	910 mA
IDD1 (Operating one bank active-read-precharge current)	1,030 mA
IDD2P (Precharge power-down current)	125 mA
IDD3N (Active standby current)	760 mA
IDD6 (Self refresh current)	125 mA

* At 85 - 95 °C operation temperature range, doubling refresh commands in frequency to a 32ms period (tREFI=3.9 us) is required, and to enter to self refresh mode at this temperature range, an EMRS command is required to change internal refresh rate.

Physical Dimension (drawing not in scale) Units : in Millimeters

